

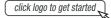
Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.33 \text{ V}$ at $I_F = 5.0 \text{ A}$



DESIGN SUPPORT TOOLS





| PRIMARY CHARACTERISTICS | | | | |
|-----------------------------------------|-------------------------------|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | |
| V _{RRM} | 45 V | | | |
| I _{FSM} | 160 A | | | |
| V _F at I _F = 10 A | 0.41 V | | | |
| T _J max. | 150 °C | | | |
| Package | D ² PAK (TO-263AB) | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

• High efficiency operation

(e3)

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

RoHS COMPLIANT

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|------------------------------------------------------------------------------------|------------|-----------------------------------|-------------|------|--|
| PARAMETER | | SYMBOL | VBT2045C | UNIT | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 45 | V | |
| Maximum average forward rectified current (fig. 1) | per device | I= | 20 | ^ | |
| | per diode | I _{F(AV)} | 10 | A | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 160 | А | |
| Operating junction and storage temperature range | | T _J , T _{STG} | -40 to +150 | °C | |



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|-----------------------------------------------------------------------------------|-----------------------------------------------|---------------------------------------------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.44 | - | V |
| | I _F = 10 A | | | 0.49 | 0.58 | |
| | I _F = 5 A | T _A = 125 °C | | 0.33 | - | |
| | I _F = 10 A | | | 0.41 | 0.52 | |
| Reverse current per diode | V _R = 45 V | $T_A = 25 ^{\circ}\text{C}$ $T_A = 125 ^{\circ}\text{C}$ | I _R ⁽²⁾ | - | 2000 | μA |
| | V _R = 45 V T _A = 125 °C | IR ^(−) | 10 | 30 | mA | |

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|-------------------------------------------------------------------------|------------|---------------|----------|------|--|
| PARAMETER | | SYMBOL | VBT2045C | UNIT | |
| Typical thermal resistance | per diode | $R_{	hetaJC}$ | 3.0 | °C/W | |
| | per device | | 2.0 |] | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-263AB | VBT2045C-E3/4W | 1.38 | 4W | 50/tube | Tube | |
| TO-263AB | VBT2045C-E3/8W | 1.38 | 8W | 800/reel | Tape and reel | |

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

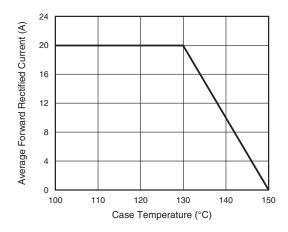


Fig. 1 - Maximum Forward Current Derating Curve

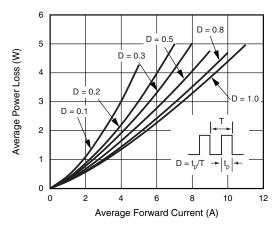


Fig. 2 - Forward Power Loss Characteristics Per Diode



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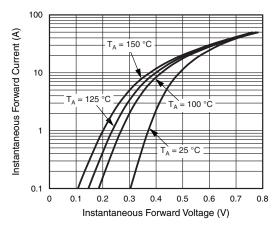


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

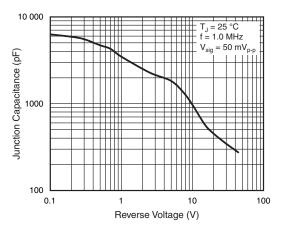


Fig. 5 - Typical Junction Capacitance Per Diode

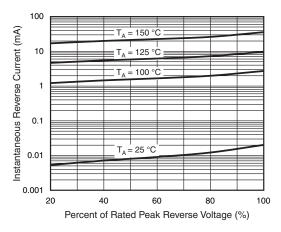


Fig. 4 - Typical Reverse Characteristics Per Diode

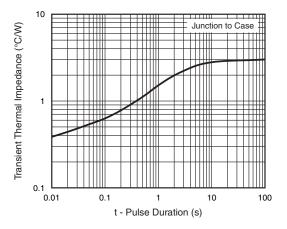
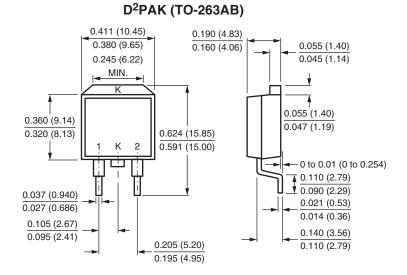
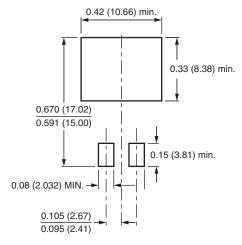


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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